

VS-1ENH01HM3, VS-1ENH02HM3

Vishay Semiconductors

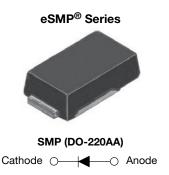
AUTOMOTIVE GRADE

RoHS

COMPLIANT HALOGEN

FREE

Ultrafast Rectifier, 1 A FRED Pt®



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	1 A			
V_{R}	100 V, 200 V			
V _F at I _F	0.69 V			
I _{FSM}	40 A			
t _{rr} (typ.)	23 ns			
T _J max.	175 °C			
Package	SMP (DO-220AA)			
Circuit configuration	Single			

FEATURES

- Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- For PFC, CRM snubber operation
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber, industrial, and automotive applications.

MECHANICAL DATA

Case: SMP (DO-220AA)

Molding compound meets UL 94 V-0 flammability rating **Terminals:** matte tin plated leads, solderable per

J-STD-002, meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse	VS-1ENH01HM3			100	V
voltage	VS-1ENH02HM3	V_{RRM}		200	
Average rectified forward current		I _{F(AV)}	T _C = 168 °C	1	۸
Non-repetitive peak surge current		I _{FSM}	$T_J = 25$ °C, 10 ms sine pulse	40	А
Operating junction and storage temperatures		T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage,	VS-1ENH01HM3	V _{BR} ,	1 100	100	-	-			
blocking voltage	VS-1ENH02HM3	V_R $I_R = 100 \mu A$		200	-	-	V		
Familiand with the			I _F = 1 A	-	0.86	0.92	v		
Forward voltage		V_{F}	٧F	V F	I _F = 1 A, T _J = 150 °C	-	0.69	0.74	
Reverse leakage current		ı	V _R = V _R rated	-	-	2	μА		
		IR	T _J = 150 °C, V _R = V _R rated	-	-	20			
Junction capacitance		C _T	V _R = 200 V	-	8	-	pF		

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
Reverse recovery time t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	23	-		
		$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	28]
	Lrr T	T _J = 25 °C	I _F = 1 A	-	14	-	ns - A
		T _J = 125 °C		=	22	-	
Dools woods on a surrent	Bud was a second	T _J = 25 °C		=	1.7	-	
Peak recovery current I _{RRM}	T _J = 125 °C	$dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 100 \text{ V}$	_	2.7	-		
Reverse recovery charge Q _{rr}	T _J = 25 °C		-	10	-	nC	
	T _J = 125 °C		-	29	=	110	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and s	storage temperature	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to mount		R _{thJM} ⁽¹⁾	Infinite heatsink	-	7	9	°C/W
Thermal resistance, junction to ambient		R _{thJA}	PCB footprint 4.8 mm x 4.8 mm	-	107	-	C/VV
Approximate weight				0.024		g	
Marking daying	VS-1ENH01HM3		Case style SMP (DO-220AA)		1H1		
Marking device	VS-1ENH02HM3				1H2		

Note

⁽¹⁾ Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

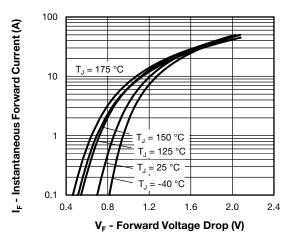


Fig. 1 - Typical Forward Voltage Drop Characteristics

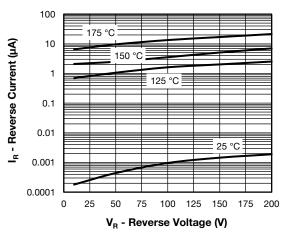


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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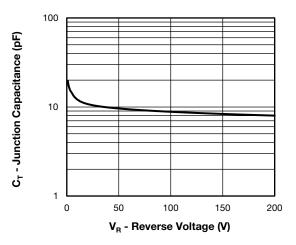


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

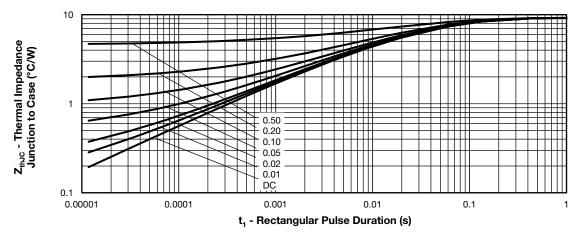


Fig. 4 - Transient Thermal Impedance, Junction to Case

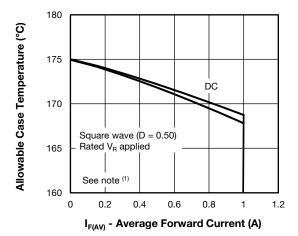


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

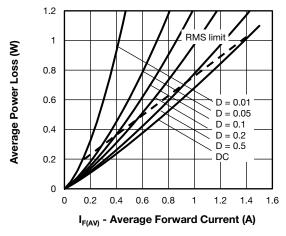


Fig. 6 - Forward Power Loss Characteristics

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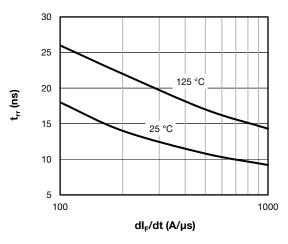


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

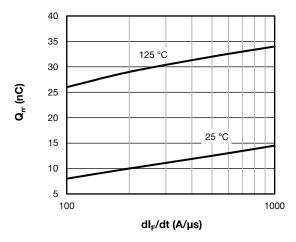
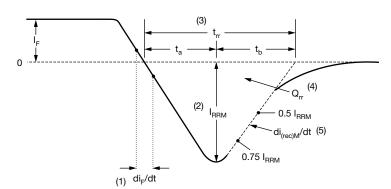


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 5); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = rated V_R



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_{F} to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

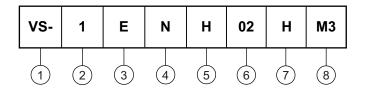
Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (1 = 1 A)

Circuit configuration:

E = single diode

4 - N = SMP package

5 - Process type,

H = ultrafast recovery

6 - Voltage code (02 = 200 V)

7 - H = AEC-Q101 qualified

8 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-1ENH01HM3/84A	84A	3000	7" diameter plastic tape and reel			
VS-1ENH01HM3/85A	85A	10 000	13" diameter plastic tape and reel			
VS-1ENH02HM3/84A	84A	3000	7" diameter plastic tape and reel			
VS-1ENH02HM3/85A	85A	10 000	13" diameter plastic tape and reel			

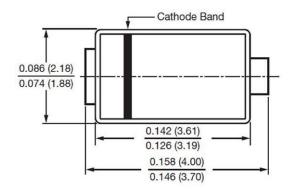
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96547</u>				
Part marking information	www.vishay.com/doc?96574			
Packaging information	www.vishay.com/doc?88869			
SPICE model	www.vishay.com/doc?96550			

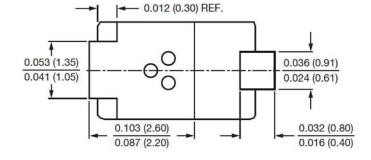


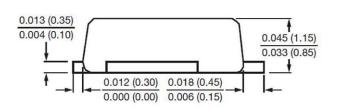
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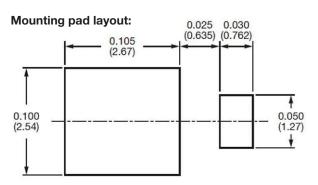
SMP (DO-220AA)

DIMENSIONS in inches (millimeters)











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